NSN 5961-01-629-4919

A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-629-4919 **Overall Length:** 0.114 inches **Overall Height:** 0.040 inches **Overall Width:** 0.061 inches **Function For Which Designed:** Switching **Features Provided:** Very high speed Voltage Rating In Volts Per Characteristic: 30.0 reverse voltage, peak **Current Rating Per Characteristic:** 600.0 milliamperes forward current, nonrepetitive, peak total value and 200.0 milliamperes forward current, dc **Capacitance Rating In Picofarads:** 10.0 **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Product Name:** Diode, dual common cathode schottky barrier **Terminal Type And Quantity:** 3 beam lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: